

# Silicon Power Transistors

The MJ21193 and MJ21194 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

- Total Harmonic Distortion Characterized
- High DC Current Gain –  
 $h_{FE} = 25 \text{ Min @ } I_C = 8 \text{ Adc}$
- Excellent Gain Linearity
- High SOA: 2.5 A, 80 V, 1 Second

## MAXIMUM RATINGS

Rating	Sym- bol	Value	Unit
Collector–Emitter Voltage	$V_{CEO}$	250	Vdc
Collector–Base Voltage	$V_{CBO}$	400	Vdc
Emitter–Base Voltage	$V_{EBO}$	5	Vdc
Collector–Emitter Voltage – 1.5 V	$V_{CEX}$	400	Vdc
Collector Current — Continuous Peak <sup>(1)</sup>	$I_C$	16 30	Adc
Base Current — Continuous	$I_B$	5	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate Above $25^\circ\text{C}$	$P_D$	250 1.43	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J$ , $T_{stg}$	–65 to +200	$^\circ\text{C}$

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.7	$^\circ\text{C/W}$

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
----------------	--------	-----	---------	-----	------

## OFF CHARACTERISTICS

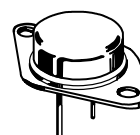
Collector–Emitter Sustaining Voltage ( $I_C = 100 \text{ mAdc}$ , $I_B = 0$ )	$V_{CEO(sus)}$	250	—	—	Vdc
Collector Cutoff Current ( $V_{CE} = 200 \text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	—	—	100	$\mu\text{Adc}$

(1) Pulse Test: Pulse Width = 5  $\mu\text{s}$ , Duty Cycle  $\leq 10\%$ . (continued)

**PNP**  
**MJ21193\***  
**NPN**  
**MJ21194\***

\*ON Semiconductor Preferred Device

**16 AMPERE  
COMPLEMENTARY  
SILICON POWER  
TRANSISTORS  
250 VOLTS  
250 WATTS**



**CASE 1-07  
TO-204AA  
(TO-3)**

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

# MJ21193 MJ21194

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
----------------	--------	-----	---------	-----	------

### OFF CHARACTERISTICS

Emitter Cutoff Current ( $V_{CE} = 5\text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	—	—	100	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CE} = 250\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ )	$I_{CEX}$	—	—	100	$\mu\text{Adc}$

### SECOND BREAKDOWN

Second Breakdown Collector Current with Base Forward Biased ( $V_{CE} = 50\text{ Vdc}$ , $t = 1\text{ s}$ (non-repetitive)) ( $V_{CE} = 80\text{ Vdc}$ , $t = 1\text{ s}$ (non-repetitive))	$I_{S/b}$	5 2.5	— —	— —	$\text{Adc}$
---	-----------	----------	--------	--------	--------------

### ON CHARACTERISTICS

DC Current Gain ( $I_C = 8\text{ Adc}$ , $V_{CE} = 5\text{ Vdc}$ ) ( $I_C = 16\text{ Adc}$ , $I_B = 5\text{ Adc}$ )	$h_{FE}$	25 8	— —	75	
Base-Emitter On Voltage ( $I_C = 8\text{ Adc}$ , $V_{CE} = 5\text{ Vdc}$ )	$V_{BE(on)}$	—	—	2.2	$\text{Vdc}$
Collector-Emitter Saturation Voltage ( $I_C = 8\text{ Adc}$ , $I_B = 0.8\text{ Adc}$ ) ( $I_C = 16\text{ Adc}$ , $I_B = 3.2\text{ Adc}$ )	$V_{CE(sat)}$	— —	— —	1.4 4	$\text{Vdc}$

### DYNAMIC CHARACTERISTICS

Total Harmonic Distortion at the Output $V_{RMS} = 28.3\text{ V}$ , $f = 1\text{ kHz}$ , $P_{LOAD} = 100\text{ W}_{RMS}$  ed (Matched pair $h_{FE} = 50 @ 5\text{ A}/5\text{ V}$ )	$T_{HD}$	— —	0.8 0.08	— —	%
Current Gain Bandwidth Product ( $I_C = 1\text{ Adc}$ , $V_{CE} = 10\text{ Vdc}$ , $f_{test} = 1\text{ MHz}$ )	$f_T$	4	—	—	$\text{MHz}$
Output Capacitance ( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f_{test} = 1\text{ MHz}$ )	$C_{ob}$	—	—	500	$\text{pF}$

(1) Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2\%$

PNP MJ21193

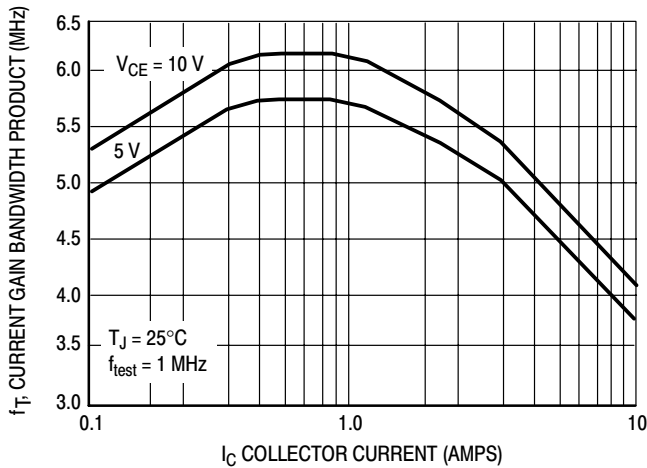


Figure 1. Typical Current Gain Bandwidth Product

NPN MJ21194

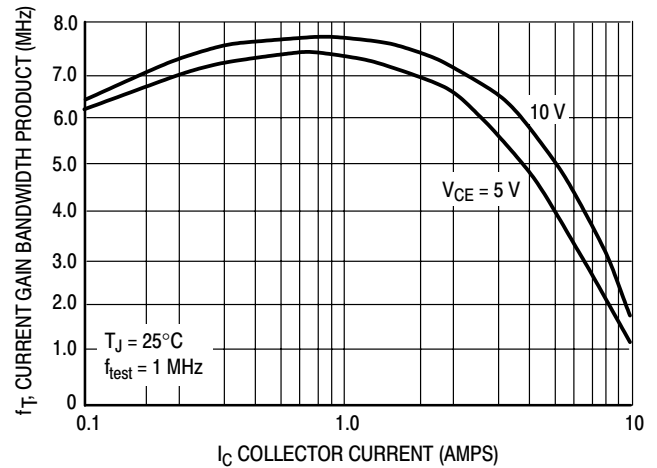


Figure 2. Typical Current Gain Bandwidth Product

TYPICAL CHARACTERISTICS

PNP MJ21193

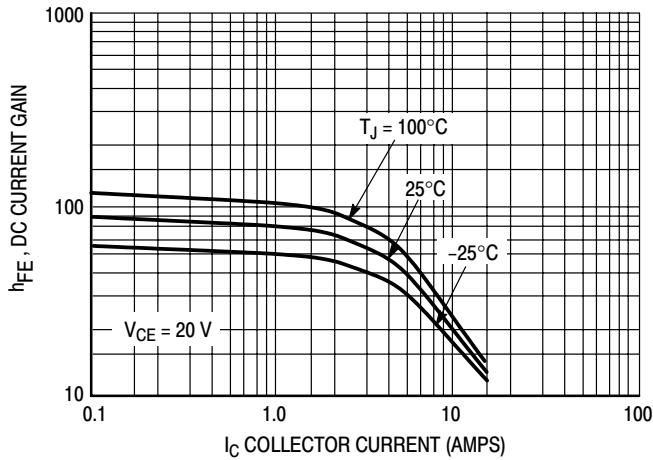


Figure 3. DC Current Gain,  $V_{CE} = 20\text{ V}$

NPN MJ21194

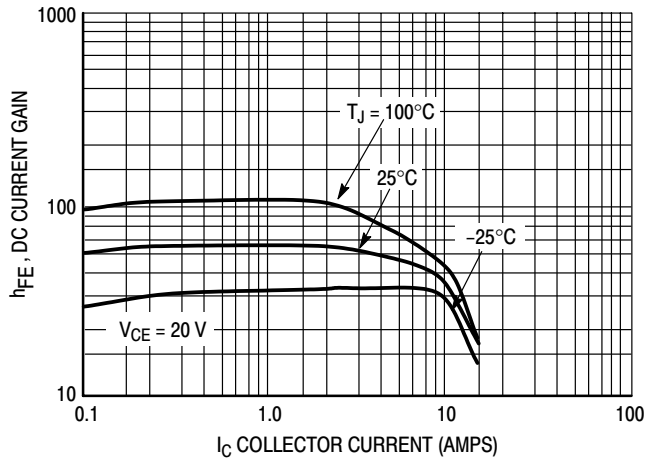


Figure 4. DC Current Gain,  $V_{CE} = 20\text{ V}$

PNP MJ21193

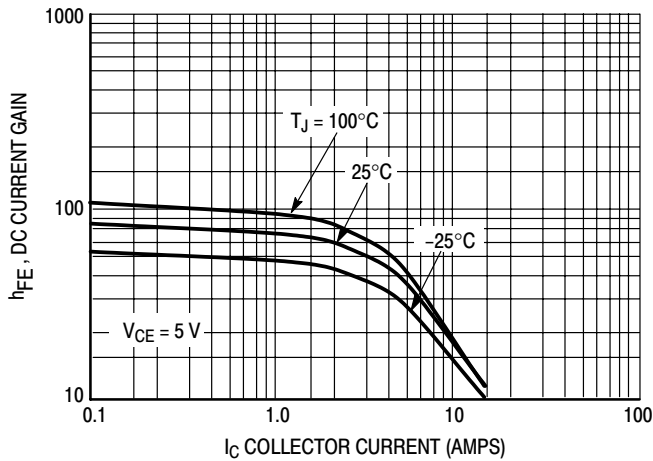


Figure 5. DC Current Gain,  $V_{CE} = 5\text{ V}$

NPN MJ21194

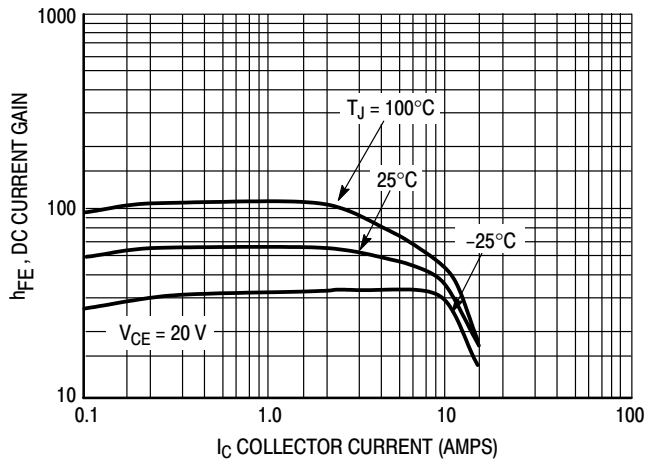


Figure 6. DC Current Gain,  $V_{CE} = 5\text{ V}$

PNP MJ21193

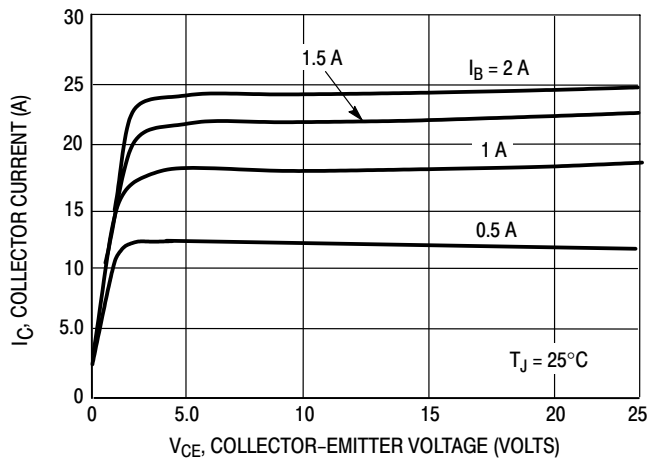


Figure 7. Typical Output Characteristics

NPN MJ21194

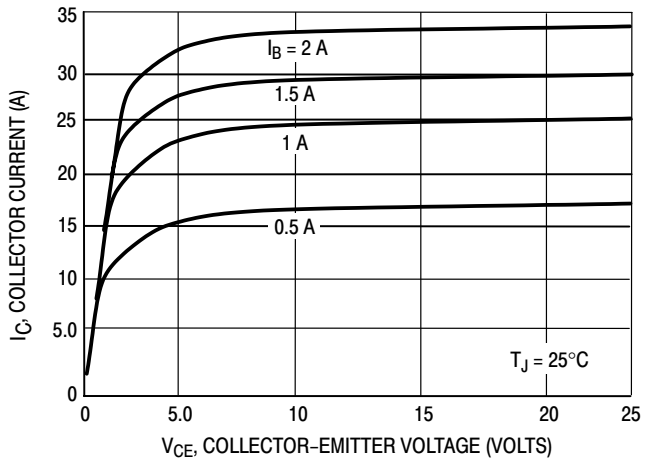


Figure 8. Typical Output Characteristics

TYPICAL CHARACTERISTICS

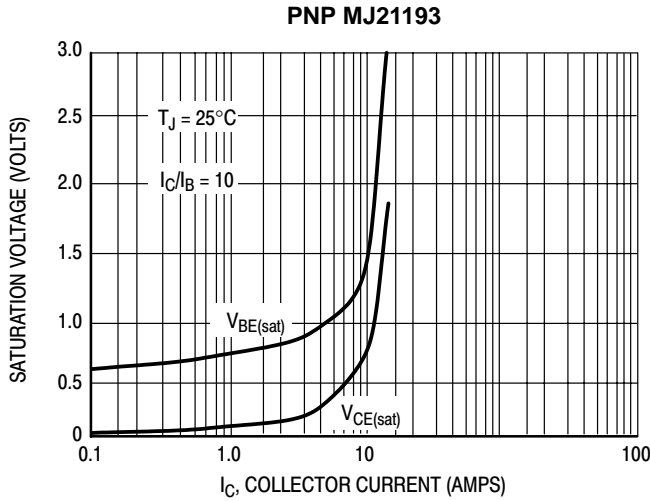


Figure 9. Typical Saturation Voltages

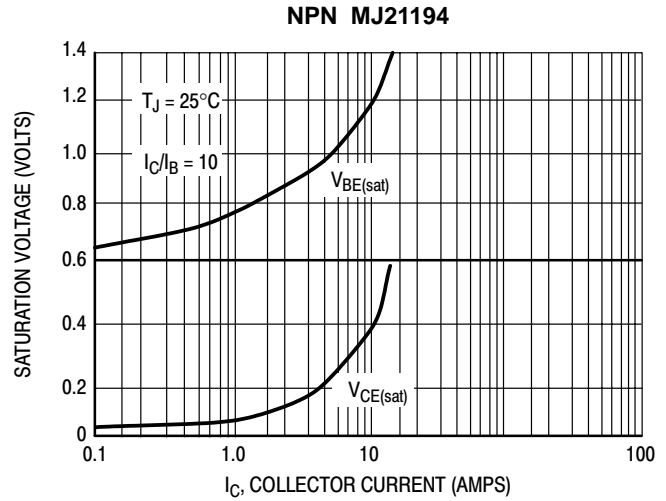


Figure 10. Typical Saturation Voltages

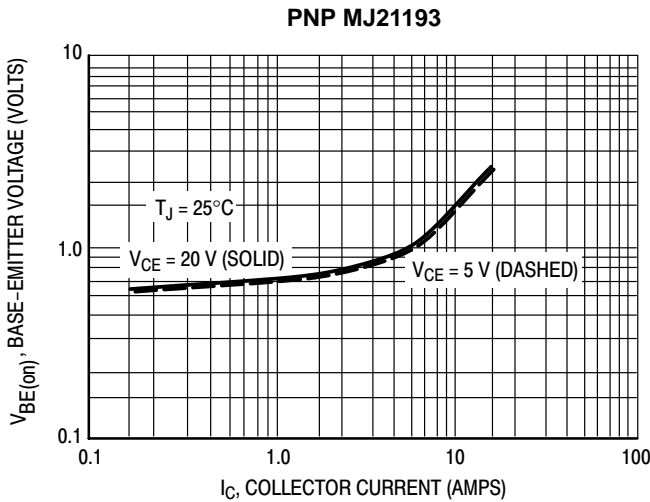


Figure 11. Typical Base-Emitter Voltage

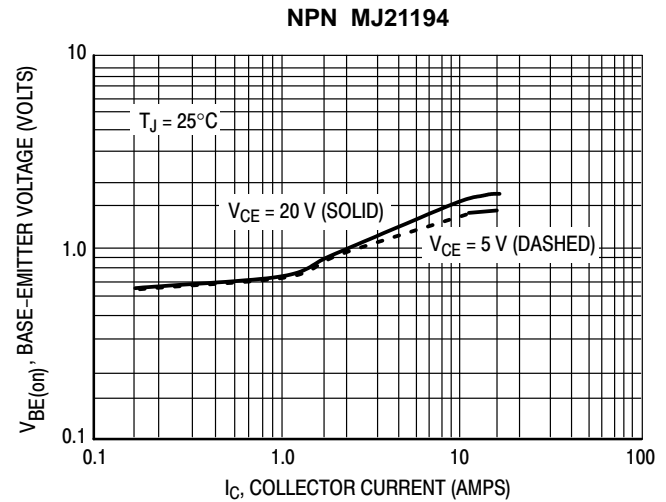


Figure 12. Typical Base-Emitter Voltage

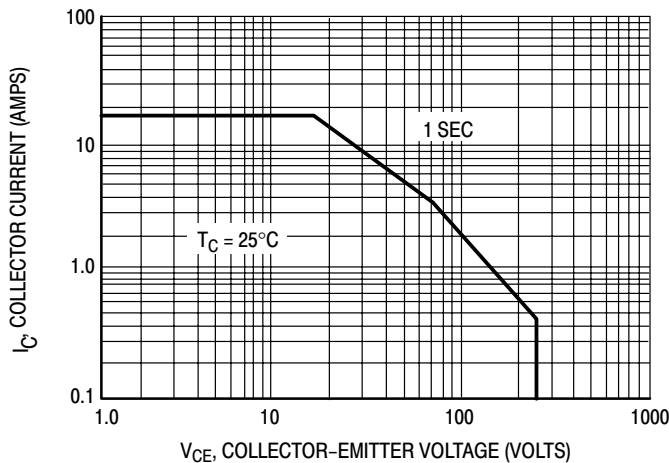


Figure 13. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on  $T_{J(pk)} = 200^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

## MJ21193 MJ21194

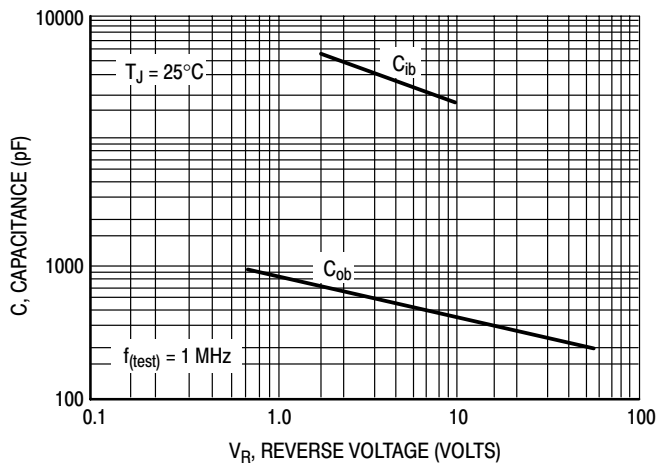


Figure 14. MJ21193 Typical Capacitance

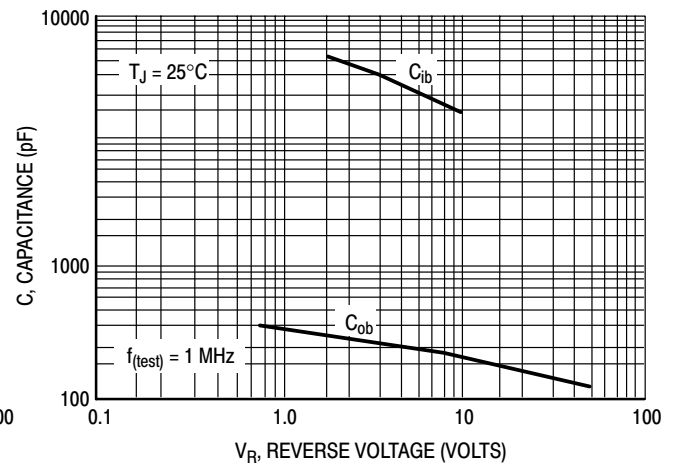


Figure 15. MJ21194 Typical Capacitance

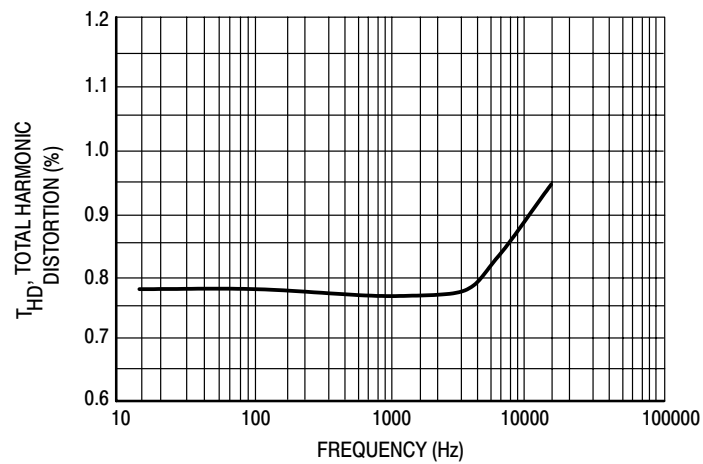


Figure 16. Typical Total Harmonic Distortion

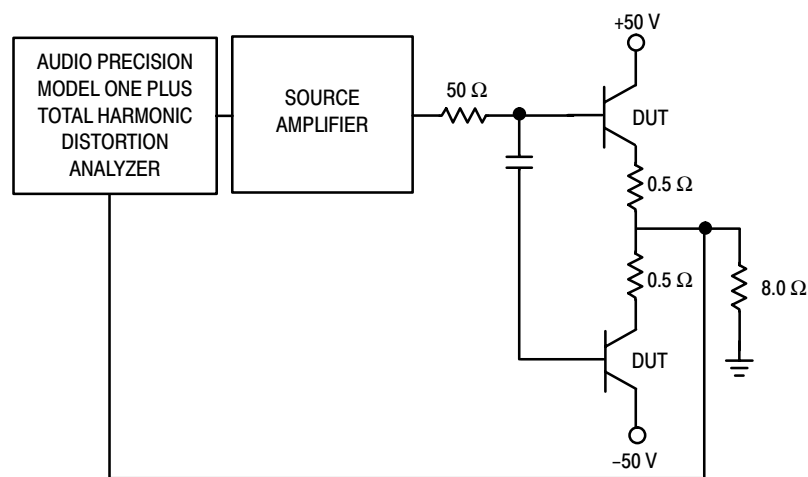


Figure 17. Total Harmonic Distortion Test Circuit



## **Notes**

**ON Semiconductor** and  are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

## PUBLICATION ORDERING INFORMATION

### NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** ONlit@hibbertco.com  
Fax Response Line: 303-675-2167 or 800-344-3810 Toll Free USA/Canada

**N. American Technical Support:** 800-282-9855 Toll Free USA/Canada

**EUROPE:** LDC for ON Semiconductor – European Support

**German Phone:** (+1) 303-308-7140 (Mon-Fri 2:30pm to 7:00pm CET)  
**Email:** ONlit-german@hibbertco.com

**French Phone:** (+1) 303-308-7141 (Mon-Fri 2:00pm to 7:00pm CET)  
**Email:** ONlit-french@hibbertco.com

**English Phone:** (+1) 303-308-7142 (Mon-Fri 12:00pm to 5:00pm GMT)  
**Email:** ONlit@hibbertco.com

**EUROPEAN TOLL-FREE ACCESS\*: 00-800-4422-3781**

\*Available from Germany, France, Italy, UK, Ireland

### CENTRAL/SOUTH AMERICA:

**Spanish Phone:** 303-308-7143 (Mon-Fri 8:00am to 5:00pm MST)  
**Email:** ONlit-spanish@hibbertco.com

**Toll-Free from Mexico:** Dial 01-800-288-2872 for Access –  
then Dial 866-297-9322

**ASIA/PACIFIC:** LDC for ON Semiconductor – Asia Support

**Phone:** 1-303-675-2121 (Tue-Fri 9:00am to 1:00pm, Hong Kong Time)  
**Toll Free from Hong Kong & Singapore:**

**001-800-4422-3781**

**Email:** ONlit-asia@hibbertco.com

**JAPAN:** ON Semiconductor, Japan Customer Focus Center

4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-0031  
**Phone:** 81-3-5740-2700

**Email:** r14525@onsemi.com

**ON Semiconductor Website:** <http://onsemi.com>

For additional information, please contact your local  
Sales Representative.